X-ray optics technology at High Energy Photon Source (HEPS)

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Challenges of optics at HEPS

booster

long beam line

storage ring and experiment hall

laboratory building

guest house building

HEPS is located in Huairou Science City 80km away from Beijing down town.

Beam energy GeV 6 Emittance ≤60 pm•rad Photon energy range 0.1-300 keV >1022 **Brightness** phs/s/mm²/mrad²/0.1%BW Circumference 1360.4 m **Beamlines capacity** 15 BLs in Phase I ≥90

High

Energy



■From DLS to DLSR, X-ray optics is the key.

Low β	HEPS	EBS	APS-U	PETRA- III	ESRF	Spring- 8	APS	MAX-IV	NSLS-II
Horizontal Size (µm)	8.8	27.2	14.5	34.6	37.4	301	275	42-54	42
Vertical Size (µm)	2.3	3.4	2.8	6.3	3.5	6	10	2-4	2.9
Horizontal Diver. (µrad)	3.1	5.2	2.9	28.9	106.9	12	11	4.7-6.1	21
Vertical Diver. (µrad)	1.2	1.4	1.5	1.6	1.2	1.1	3.5	1-2	2.7



Theoretical diffraction limit (~100%)



Technical diffraction limit (~25%)



Advanced 3G SR -> HEPS Coherence ratio ~0.2% -> ~20%

Challenges



Why dose ~µm size electron beam, require ~sub-nm optics?



Challenges

S

Accuracy requirements of HEPS mirror based on partially coherent optics





- ~20nrad for low frequency
- ~1nm for high frequency (Large range)



R&D of optical elements and equipment

Ontical alamanta	Focusing Reflection Diffraction Dressesi		Processing	Matrology	Manipulation			
Optical elements	 correction 	Refraction	Processing	wetrology	Dynamic	Thermal	Environment	
Mirror	••	•		Ultimate accuracy	Ultimate resolution and stability			
Crystal	••	••						
Grating	••	••						
Bragg ML	••	••			Dynamically adjustable			
Laue ML	•	•	Ultimate precision					
Zone plate	•	•						
Kinoform Lens	•	••			Shape	Cooling	Temperature	
CRLs	••	•			Posture	Adjustable	Vibration	
Phase Plate	•	•						

Optics and beamline design

Beamline

Revolution in beamline design and construction

- The design concept and organization of the beamline have undergone fundamental changes.
- The transformation towards systematic engineering is the technology integration and optimization under the guidance of the new X-ray optics theory.



X-ray optics

A wave-optics simulation based on a coherent modes decomposition and a wavefront propagation model.

The simulation software, Coherence Analysis Toolbox (CAT)



Source (IVU) coherent modes distribution



Coherent mode at focusing point

Used in BL design



Dynamical diffraction theory

Developing a general numerical framework for X-ray diffractive optics based on the Takagi–Taupin (TT) dynamical theory with a general integral system of the TT equations formed for the FEA



Used in HEPS-TF and HEPS For high-energy-resolution/high-energy monochromators designs



Also used in HEPS-TF and HEPS

For multilayer devices in B2 nano-probe/B3 dynamic structure/B6 high pressure

Yuhang Wang, Optics Express 28 (2020)



Mango: A new type of Wiggler for Large FOV Imaging



Magnetic field

Flux angle distribution in FOV

Delta type magnetic structure

To be published



Sep. 22, 2023

R&D status of optics technology

Developing the theories of bent mirrors

Basic Theory:





1m ellipitical bent mirror



Bending shape accuracy RMS 0.17µrad

Stability: 72h, deformation 66nrad RMS

Short bent mirror



We use this longitudinal translation structure firstly in the world.



	Measuring Results			
effective length	120mm (146mm total)			
Bending Shape	Designed Ellipse(40m, 120mm, 3mrad)			
Bending shape accuracy	0.13μ rad(HFM)			
(Bent mirror shape – Bare mirror shape – Designed e	llipse) 0.19μrad (VFM)			
0.0003 0.0002 0.0001 0.0001 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000 0.0000				
Position,m	Position,m Position,mm			
4.×10 ⁻⁷ 2.×10 ⁻⁷ 0 A. M A A A A A A A A A A A A A A A A A				

⁸/₉ −2. × 10⁻⁷/_{-4. × 10⁻⁷} -0.06 −0.04 −0.02 0.00 0.02 0.04 0.06 Position,m Position,m Position,m

Bending shape accuracy RMS 0.13µrad & 0.19µrad

Stability: 72h, transformation 6nrad RMS

60

Position,mm

80

40

120

100

20

Next Bending Techniques in HEPS

— Zoom capability and optimized design

For example: p=20.3m, q=0.18m, L=0.2m, $\theta=2.2$ mrad HFM



Active mirror



Fugui Yang, Ming Li*, Lidan Gao, Weifan Sheng, Peng Liu, and Xiaowei Zhang, "Laser-heating-based active optics for synchrotron radiation applications," Opt. Lett. 41, 2815-2818 (2016)

Thermal management

➢ Highly efficient thermal deformation optimization method

Smart-cut mirrors over the entire photon energy range

 ➢ By optimizing the notches of water-cooled whitebeam mirrors, the RMS of the curvatures of the thermal deformation of the white-beam mirror over the entire photon energy range is minimized.
 Considerably simplifies design of all of the watercooled white-beam mirrors

1.5 FEA fitting curvature(Si) ▼ FEA fitting curvature(Rh) Curvature [$\times 10^{-7}$ /m] -FEA fitting curvature(Pt) Theoretical curvature(Si) 0.5 Theoretical curvature(Rh) Theoretical curvature(Pt) 0 -0.5 -1 -1.5 15 20 25 30 35 10 40 45 5 Energy [keV]

The method has been used for all the thermal deformation analysis of all mirrors.

Shaofeng Wang[‡], Dongni Zhang[‡], Ming Li^{*}, Lidan Gao, Minwei Chen, Fugui Yang and Weifan Sheng, "Highly efficient thermal deformation optimization method for smart-cut mirrors over the entire photon energy range" J. Synchrotron Rad. (2022). 29, 1152–1156



Optical metrology (Flag-type Surface Profiler, FSP)



S

To be published

Accuracy of measurement for plane/curved mirror

Spatial resolution 1mm (Slope error is sensitive to spatial resolution)

Accuracy for plane mirror measurement: RMS 24.5 nrad



Accuracy for Curved mirror: RMS 29.0 nrad / RMS 0.23nm







Position.mm





Measurement of the mirror of B4 beamline (Curve, 0.1nm RMS)



Length 415mm





Specification Mirror Shape **Parameter** Measurement Elliptical 35nrad **Slope error RMS** 50nrad Hyperbolic 41nrad **B4-Wolter** Elliptical 0.11nm/0.59nm **Height error** 0.4nm / 6nm **RMS/PV** 0.12nm/0.7nm Hyperbolic



1mm resolution



Position.mm



1mm resolution



Stitching Interferometer

Surface metrology during fabrication





Proposed SI based on angular measurement

The proposed θ-R method is used in metrology of severe curvature crystal

Stitching Interferometer





A Frequency-decomposed Stitching Interferometer (FSI) has been proposed and developed, which can provide feedback for mirror processing with sub-nanometer accuracy.



Near-Field Speckle Based Wavefront Metrology

0.006

0.004

0.000

-0.002

-0.004

-0.008

-0.001

-0.010

laser microsco

XST vertical

Independent Variable (mm)

Develop speckle based wavefront metrology at SSRF





CRL measurement results compare with confocal laser scanning microscopy, (a)Height profile, (b)Residual error



XST method and XSVT method for CRL sample, (a) Height profile, (b)Residual error

Develop speckle based wavefront metrology based on X-ray microfocus source



Online wavefront measurement

Double-edge scan wavefront measurement



- Solving the problems of coherence, stability, distortion of wavefront in 1GSR
- Successful application in BSRF <1pm precision



(a) Equivalent Bragg diffraction surface slope error profiles of three measurements and average profile.
(b) The deviations from the average of the three measurements slope error profiles. (c) Wavefront height error profiles of three measurements and average profile. (d) The deviations from the average of the three measurements wavefront height error profiles.

Measurement precision ~14 nrad and <1 pm RMS

Fabrication of wavefront-preserved crystals



The quality of crystals satisfy the requirements of 4GSR.

Channel-Cut crystal





Double-edge wavefront measurement

Analysis crystals





- Spherically bent analyzers for XRS: excellent focusing & energy resolution
- Bent-striped analyzers for XRS: energy resolution improved
- Mosaic-diced analyzers for RIXS: highly improved energy resolution

Test and installation- endstation instrumentation

X-ray Raman spectrometer prototype module tested at BSRF



Prototype module



X-ray Raman signals







Multilayer Laue Lens (MLL)





Magnetron sputtering



Growth rate drift 0.3%



Position error (PV) ±5nm, simulated focus spot 8nm. Fulfilled the demand of nano-probe

Multilayer devices

Coating on mirrors



Gradient multilayer mirror





Thickness error ±0.35%(pv) Precision: 6.5pm(rms)







Energy resolution: 4.1%

Coating: Pt, Ni, B4C

Reflectivity: 75%

Refractive lens

Ni-based kinoform

Tested in PETRA III, focus spot 4µm@87keV

Used in HEPS B1





Ni-based kinoform



Ni-based kinoform



1D SU8-based CRL



CRL profile



50 100 150 200 250 300 350 400 Position μm Shape profile error 0.75μm RMS

0



Mirror Fabrication (collaborate with other Chinese institute)

- > 500mm 0.3µrad flat mirror
- > 300mm 1µrad elliptical mirror
- > 0.2nm~0.3nm roughness













230mm elliptical ~1μrad @ 2mm resolution

Monochromators for high stability and coherence preserving





VDCM



HDCM



Fast-scan DCM **Time resolved XAFS**







Details also in THOBM03

HR-4BCM High energy resolution



Deformation of crystals with clamping under cryo temperature < 0.1µrad RMS (after removal of 2nd order)

5-500Hz 0 RMS. pitch 0.5 1.0 1.5 2.0 2.5 3.0 3.5 4.0 4.5 0.0 Flow Rate (L/min)

RMS displacement (nrad) Pitch, NO LN2 Roll, NO LN2 0 1 10 100 Frequency (Hz)

Stability of VDCM <10nrad RMS **Under cooling**

Stability of HDCM Without cooling

Fast-scan DCM **100 XAFS spectra /s** @50Hz 0.8°

Detector

1. Pixel array detector



Single module of the PAD used in HEPS Mass production





Parameters	1 st generation	2 nd generation –new		
Sensor	320um silicon PIN	320-500μm		
Pixel size	150umX150um	140umX140um		
Pixel array	1248X1728 (single module 208X288, 4X6 modules)	Single module 256×576 pixels (3.6cm×8cm)		
Counting rate	1Mcps	>1Mcps		
Dynamic range	20bit	20bit		
Flame rate	1KHz (design), continuous read-out 100Hz	1KHz continuous read-out		
Energy range	8-20keV	>6keV		
Threshold	single	Double		
Death point	<1‰	<1‰		
Gap	1.6mmX2.5mm	1.2mm×2.8mm		



2, XBPM: (Diamond four-quadrant XBPM)



- Senser
- Electronic

3、 nanosecond time resolution detector. (APD)



- 4、SDD
 - Senser + ASIC + Packaging
 - 150eV@5.9keV, 1Mcps/channel。



200

Al-drived optics manipulation

Beamline alignment:



Data management and analysis



Data acquisition and beamline/end-station control: MAMBA Data management: DOMAS Data analysis: DAISY



HEPS, a powerful 4G light source, brings severe challenges to optics technology.

Towards the challenges of diffraction limited optics, we have done a lot of R&D work, including metrology, processing, manipulation, detector and so on.

Some challenges of optics technology have been solved by ourselves.

Thank you for your attention!